Member of the Texas Instruments Widebus+™ Family

- Optimized for 1.8-V Operation and is 3.6-V I/O Tolerant to Support Mixed-Mode Signal Operation
- I_{off} Supports Partial-Power-Down Mode Operation
- Sub 1-V Operable
- Max t_{pd} of 1.8 ns at 1.8 V

description/ordering information

Low Power Consumption, 40-μA Max I_{CC}

SN74AUC32244

SCES425 - FEBRUARY 2003

32-BIT BUFFER/DRIVER WITH 3-STATE OUTPUTS

- ±8-mA Output Drive at 1.8 V
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22 – 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)

This 32-bit buffer/driver is operational at 0.8-V to 2.7-V V_{CC}, but is designed specifically for 1.65-V to 1.95-V V_{CC} operation.

The SN74AUC32244 is designed specifically to improve the performance and density of 3-state memory address drivers, clock drivers, and bus-oriented receivers and transmitters.

The device can be used as eight 4-bit buffers, four 8-bit buffers, two 16-bit buffers, or one 32-bit buffer. It provides true outputs and symmetrical active-low output-enable (\overline{OE}) inputs.

To ensure the high-impedance state during power up or power down, OE should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

This device is fully specified for partial-power-down applications using I_{off}. The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

ORDERING INFORMATION

TA	PACK	AGE [†]	ORDERABLE PART NUMBER	TOP-SIDE MARKING
$-40^{\circ}C$ to $85^{\circ}C$	LFBGA – GKE	Tape and reel	SN74AUC32244GKER	MM244

[†] Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



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SN74AUC32244 32-BIT BUFFER/DRIVER WITH 3-STATE OUTPUTS SCES425 - FEBRUARY 2003

GKE PACKAGE (TOP VIEW)

1 2 3 4 5 6

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в		\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc
С		\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc
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terminal assignments

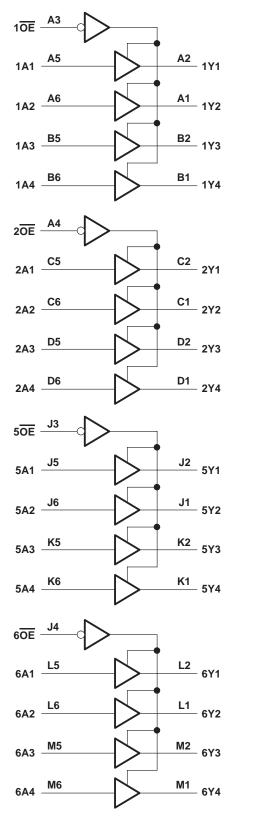
	1	2	3	4	5	6
Α	1Y2	1Y1	1 <mark>0E</mark>	2 <mark>0E</mark>	1A1	1A2
в	1Y4	1Y3	GND	GND	1A3	1A4
С	2Y2	2Y1	VCC	VCC	2A1	2A2
D	2Y4	2Y3	GND	GND	2A3	2A4
Е	3Y2	3Y1	GND	GND	3A1	3A2
F	3Y4	3Y3	V _{CC}	VCC	3A3	3A4
G	4Y2	4Y1	GND	GND	4A1	4A2
н	4Y3	4Y4	40E	3OE	4A4	4A3
J	5Y2	5Y1	50E	6OE	5A1	5A2
κ	5Y4	5Y3	GND	GND	5A3	5A4
L	6Y2	6Y1	VCC	VCC	6A1	6A2
М	6Y4	6Y3	GND	GND	6A3	6A4
Ν	7Y2	7Y1	GND	GND	7A1	7A2
Ρ	7Y4	7Y3	V _{CC}	V _{CC}	7A3	7A4
R	8Y2	8Y1	GND	GND	8A1	8A2
т	8Y3	8Y4	8OE	7OE	8A4	8A3

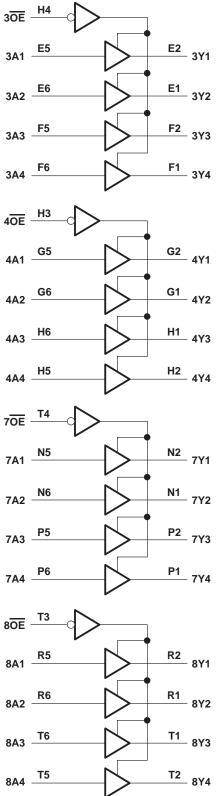
FUNCTION TABLE (each 4-bit buffer)

INPU	JTS	OUTPUT
OE	Α	Y
L	Н	Н
L	L	L
Н	Х	Z



logic diagram (positive logic)







SN74AUC32244 32-BIT BUFFER/DRIVER WITH 3-STATE OUTPUTS SCES425 - FEBRUARY 2003

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

Supply voltage range, V _{CC} Input voltage range, V _I (see Note 1) Voltage range applied to any output in the high-impedance or power-off st	–0.5 V to 3.6 V
(see Note 1)	
Output voltage range, V _O (see Note 1)	$\dots \dots -0.5$ V to V _{CC} + 0.5 V
Input clamp current, I _{IK} (V _I < 0)	–50 mA
Output clamp current, I _{OK} (V _O < 0)	–50 mA
Continuous output current, I _O	±20 mA
Continuous current through V _{CC} or GND	±100 mA
Package thermal impedance, θ_{JA} (see Note 2)	
Storage temperature range, T _{stg}	–65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

2. The package thermal impedance is calculated in accordance with JESD 51-7.

recommended operating conditions (see Note 3)

			MIN	MAX	UNIT
VCC	Supply voltage		0.8	2.7	V
		$V_{CC} = 0.8 V$	VCC		
VIH	High-level input voltage	$V_{CC} = 1.1 \text{ V to } 1.95 \text{ V}$	$0.65 \times V_{CC}$		V
		V_{CC} = 2.3 V to 2.7 V	1.7		
		V _{CC} = 0.8 V		0	
VIL	Low-level input voltage	V _{CC} = 1.1 V to 1.95 V		$0.35 \times V_{CC}$	V
		V_{CC} = 2.3 V to 2.7 V		0.7	
VI	Input voltage		0	3.6	V
	Output wells are	Active state	0	VCC	
VO	Output voltage	3-state	0	3.6	V
		V _{CC} = 0.8 V		-0.7	
		V _{CC} = 1.1 V		-3	
ЮН	High-level output current	$V_{CC} = 1.4 V$		-5	mA
		V _{CC} = 1.65 V		-8	
		$V_{CC} = 2.3 V$		-9	
		V _{CC} = 0.8 V		0.7	
		V _{CC} = 1.1 V		3	
IOL	Low-level output current	V _{CC} = 1.4 V		5	mA
		V _{CC} = 1.65 V		8	
		$V_{CC} = 2.3 V$		9	
		V _{CC} = 0.8 V		20	
$\Delta t / \Delta v$	Input transition rise or fall rate	V _{CC} = 1.3 V		15	ns/V
		V_{CC} = 1.6 V, 1.95 V, and 2.7 V		10	
Тд	Operating free-air temperature		-40	85	°C

NOTE 3: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



SN74AUC32244 **32-BIT BUFFER/DRIVER** WITH 3-STATE OUTPUTS SCES425 – FEBRUARY 2003

PA	RAMETER	TEST CONDITIO	NS	Vcc	MIN	TYP [†]	MAX	UNIT
		I _{OH} = -100 μA		0.8 V to 2.7 V	V _{CC} -0.	.1		
		I _{OH} = -0.7 mA		0.8 V		0.55		
		I _{OH} = -3 mA		1.1 V	0.8			
VOH		I _{OH} = -5 mA		1.4 V	1			V
		$I_{OH} = -8 \text{ mA}$		1.65 V	1.2			
		$I_{OH} = -9 \text{ mA}$		2.3 V	1.8			
		I _{OL} = 100 μA		0.8 V to 2.7 V			0.2	
		I _{OL} = 0.7 mA		0.8 V		0.25		
.,		I _{OL} = 3 mA		1.1 V			0.3	
VOL		I _{OL} = 5 mA		1.4 V			0.4	V
		I _{OL} = 8 mA		1.65 V			0.45	
		I _{OL} = 9 mA		2.3 V			0.6	
Ц	A or OE inputs	$V_I = V_{CC}$ or GND		0 to 2.7 V			±5	μΑ
loff		V_{I} or $V_{O} = 2.7 V$		0			±10	μΑ
I _{OZ}		$V_{O} = V_{CC}$ or GND		2.7 V			±10	μΑ
ICC		$V_{I} = V_{CC}$ or GND,	I <mark>O</mark> = 0	0.8 V to 2.7 V			40	μA
Ci		$V_{I} = V_{CC}$ or GND		2.5 V		3.5	4.5	pF
Co		$V_{O} = V_{CC}$ or GND		2.5 V	1	6	7.5	pF

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

[†] All typical values are at $T_A = 25^{\circ}C$.

switching characteristics over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

PARAMETER	AMETER FROM TO (INPUT) (OUTPUT)		$V_{CC} = 0.8 V \begin{array}{c} V_{CC} = 1.2 V \\ \pm 0.1 V \end{array}$		$\begin{array}{c} \text{V}_{\text{CC}} = 1.5 \text{ V} \\ \pm \text{ 0.1 V} \end{array}$		V _{CC} = 1.8 V ± 0.15 V			V _{CC} = ± 0.	UNIT		
	(INFOT)	(001F01)	TYP	MIN	MAX	MIN	MAX	MIN	TYP	MAX	MIN	MAX	
^t pd	А	Y	5.4	0.8	2.8	0.6	1.9	0.7	1.3	1.8	0.5	1.8	ns
t _{en}	OE	Y	8	1	4.4	0.7	2.6	0.8	1.4	2.5	0.6	1.9	ns
^t dis	OE	Y	12	1.9	4.9	1	4.6	1.5	2.6	4	0.5	2	ns

operating characteristics, $T_A = 25^{\circ}C$

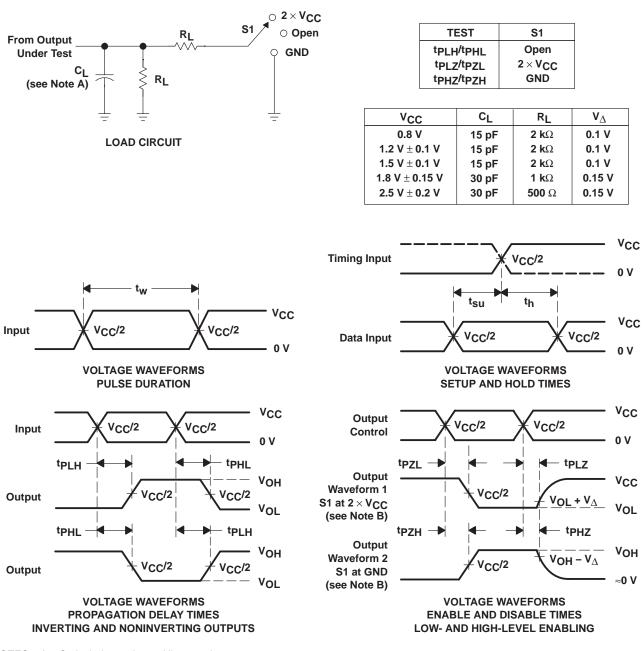
	PARAMETE	R	TEST	V _{CC} = 0.8 V	V _{CC} = 1.2 V	V _{CC} = 1.5 V	V _{CC} = 1.8 V	V _{CC} = 2.5 V	UNIT
			CONDITIONS	TYP	TYP	TYP	TYP	ТҮР	UNIT
C .	Power	Outputs enabled		21	22	23	25	30	
C _{pd}	dissipation capacitance	Outputs disabled	f = 10 MHz	1	1	1	1	1	pF



SN74AUC32244 **32-BIT BUFFER/DRIVER** WITH 3-STATE OUTPUTS

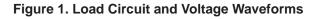
SCES425 - FEBRUARY 2003

PARAMETER MEASUREMENT INFORMATION



NOTES: A. Cl includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_Q = 50 Ω , slew rate \geq 1 V/ns.
- D. The outputs are measured one at a time with one transition per measurement.
- E. tpLz and tpHz are the same as tdis.
- F. t_{PZL} and t_{PZH} are the same as t_{en}.
- G. tPLH and tPHL are the same as tpd.
- H. All parameters and waveforms are not applicable to all devices.







27-Dec-2019

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package	Pins	Package	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
SN74AUC32244GKER	NRND	LFBGA	GKE	96	1000	TBD	SNPB	Level-2-235C-1 YEAR	-40 to 85	MM244	
SN74AUC32244ZKER	NRND	LFBGA	ZKE	96	1000	Green (RoHS & no Sb/Br)	SNAGCU	Level-3-260C-168 HR	-40 to 85	MM244	

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption. **Green:** TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AUC32244GKER	LFBGA	GKE	96	1000	330.0	24.4	5.7	13.7	2.0	8.0	24.0	Q1
SN74AUC32244ZKER	LFBGA	ZKE	96	1000	330.0	24.4	5.7	13.7	2.0	8.0	24.0	Q1

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PACKAGE MATERIALS INFORMATION

29-Sep-2019



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74AUC32244GKER	LFBGA	GKE	96	1000	336.6	336.6	41.3
SN74AUC32244ZKER	LFBGA	ZKE	96	1000	336.6	336.6	41.3

GKE (R-PBGA-N96)

PLASTIC BALL GRID ARRAY



- NOTES: A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Falls within JEDEC MO-205 variation CC.
 - D. This package is tin-lead (SnPb). Refer to the 96 ZKE package (drawing 4204493) for lead-free.



ZKE (R-PBGA-N96)

PLASTIC BALL GRID ARRAY



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Falls within JEDEC MO-205 variation CC.

D. This package is lead-free. Refer to the 96 GKE package (drawing 4188953) for tin-lead (SnPb).



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